## MC74VHCT374A

## Octal D-Type Flip-Flop with 3-State Output

The MC74VHCT374A is an advanced high speed CMOS octal flip-flop with 3-state output fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input and an output enable input. When the output enable input is high, the eight outputs are in a high impedance state.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output.

The VHCT inputs are compatible with TTL levels. This device can be used as a level converter for interfacing 3.3 V to 5.0 V , because it has full 5.0 V CMOS level output swings.

The VHCT374A input and output (when disabled) structures provide protection when voltages between 0 V and 5.5 V are applied, regardless of the supply voltage. These input and output structures help prevent device destruction caused by supply voltage-input/output voltage mismatch, battery backup, hot insertion, etc.

## Features

- High Speed: $\mathrm{f}_{\max }=140 \mathrm{MHz}(\mathrm{Typ})$ at $\mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$
- Low Power Dissipation: $\mathrm{I}_{\mathrm{CC}}=4 \mu \mathrm{~A}(\mathrm{Max})$ at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
- TTL-Compatible Inputs: $\mathrm{V}_{\mathrm{IL}}=0.8 \mathrm{~V} ; \mathrm{V}_{\mathrm{IH}}=2.0 \mathrm{~V}$
- Power Down Protection Provided on Inputs and Outputs
- Balanced Propagation Delays
- Designed for 4.5 V to 5.5 V Operating Range
- Low Noise: V ${ }_{\text {OLP }}=1.6 \mathrm{~V}$ (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance:

Human Body Model > 2000 V;
Machine Model > 200 V

- Chip Complexity: 276 FETs or 69 Equivalent Gates
- These Devices are $\mathrm{Pb}-$ Free and are RoHS Compliant

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FUNCTION TABLE

| INPUTS |  |  | OUTPUT |
| :---: | :---: | :---: | :---: |
| OE | CP | D | Q |
| L | ת | H | H |
| L | 今 | L | L |
| L | L, H, 乙 | X | No Change |
| H | X | X | Z |

ORDERING INFORMATION
See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.


Figure 1. Logic Diagram

MAXIMUM RATINGS

| Symbol | Parameter |  | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC Supply Voltage |  | -0.5 to +7.0 | V |
| $V_{\text {in }}$ | DC Input Voltage |  | -0.5 to + 7.0 | V |
| $\mathrm{V}_{\text {out }}$ | DC Output Voltage | Outputs in 3-State High or Low State | $\begin{gathered} -0.5 \text { to }+7.0 \\ -0.5 \text { to } V_{C C}+0.5 \end{gathered}$ | V |
| 1 IK | Input Diode Current |  | -20 | mA |
| IOK | Output Diode Current ( $\mathrm{V}_{\text {OUT }}$ < GND; $\mathrm{V}_{\text {OUT }}>\mathrm{V}_{\text {CC }}$ ) |  | $\pm 20$ | mA |
| $\mathrm{I}_{\text {out }}$ | DC Output Current, per Pin |  | $\pm 25$ | mA |
| Icc | DC Supply Current, $\mathrm{V}_{\mathrm{CC}}$ and GND Pins |  | $\pm 75$ | mA |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation in Still Air, | SOIC Package $\dagger$ TSSOP Package $\dagger$ | $\begin{aligned} & 500 \\ & 450 \end{aligned}$ | mW |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature |  | -65 to + 150 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
†Derating - SOIC Packages: $-7 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ from $65^{\circ}$ to $125^{\circ} \mathrm{C}$
TSSOP Package: $-6.1 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ from $65^{\circ}$ to $125^{\circ} \mathrm{C}$


Figure 2. Pin Assignment

RECOMMENDED OPERATING CONDITIONS

| Symbol |  | Parameter | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | DC Supply Voltage |  | 4.5 | 5.5 | V |
| $\mathrm{V}_{\text {in }}$ | DC Input Voltage |  | 0 | 5.5 | V |
| $V_{\text {out }}$ | DC Output Voltage | Outputs in 3-State High or Low State | $\begin{aligned} & \hline 0 \\ & 0 \end{aligned}$ | $\begin{aligned} & 5.5 \\ & \mathrm{~V}_{\mathrm{CC}} \end{aligned}$ | V |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Temperature |  | -40 | + 85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{t}_{\mathrm{r}}, \mathrm{t}_{\mathrm{f}}$ | Input Rise and Fall Time | $\mathrm{V}_{\text {CC }}=5.0 \mathrm{~V} \pm 0.5 \mathrm{~V}$ | 0 | 20 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| Symbol | Parameter | Test Conditions | $\begin{gathered} \mathrm{v}_{\mathrm{cc}} \\ \mathrm{~V} \end{gathered}$ | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=-40$ to $85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  | Min | Typ | Max | Min | Max |  |
| $\mathrm{V}_{\mathrm{IH}}$ | Minimum High-Level Input Voltage |  | 4.5 to 5.5 | 2.0 |  |  | 2.0 |  | V |
| $\mathrm{V}_{\text {IL }}$ | Maximum Low-Level Input Voltage |  | 4.5 to 5.5 |  |  | 0.8 |  | 0.8 | V |
| $\mathrm{V}_{\mathrm{OH}}$ | Minimum High-Level Output <br> Voltage $\mathrm{V}_{\text {in }}=\mathrm{V}_{\mathrm{IH}}$ or $\mathrm{V}_{\mathrm{IL}}$ | $\mathrm{I}_{\mathrm{OH}}=-50 \mu \mathrm{~A}$ | 4.5 | 4.4 | 4.5 |  | 4.4 |  | V |
|  |  | $\mathrm{I}_{\mathrm{OH}}=-8 \mathrm{~mA}$ | 4.5 | 3.94 |  |  | 3.80 |  |  |
| VoL | Maximum Low-Level Output  <br> Voltage $V_{\text {in }}=V_{I H}$ or $V_{I L}$ | $\mathrm{I}_{\mathrm{OL}}=50 \mu \mathrm{~A}$ | 4.5 |  | 0.0 | 0.1 |  | 0.1 | V |
|  |  | $\mathrm{I}_{\text {OL }}=8 \mathrm{~mA}$ | 4.5 |  |  | 0.36 |  | 0.44 |  |
| $1{ }_{\text {in }}$ | Maximum Input Leakage Current | $\mathrm{V}_{\text {in }}=5.5 \mathrm{~V}$ or GND | 0 to 5.5 |  |  | $\pm 0.1$ |  | $\pm 1.0$ | $\mu \mathrm{A}$ |
| l Oz | Maximum 3-State Leakage Current | $\begin{aligned} & V_{\text {in }}=V_{\text {IL }} \text { or } V_{\text {IH }} \\ & V_{\text {out }}=V_{\text {CC }} \text { or } G N D \end{aligned}$ | 5.5 |  |  | $\pm 0.25$ |  | $\pm 2.5$ | $\mu \mathrm{A}$ |
| Icc | Maximum Quiescent Supply Current | $\mathrm{V}_{\text {in }}=\mathrm{V}_{\text {CC }}$ or GND | 5.5 |  |  | 4.0 |  | 40.0 | $\mu \mathrm{A}$ |
| $\mathrm{I}_{\text {CCT }}$ | Quiescent Supply Current | Per Input: $\mathrm{V}_{\mathbb{I N}}=3.4 \mathrm{~V}$ Other Input: $\mathrm{V}_{\mathrm{CC}}$ or GND | 5.5 |  |  | 1.35 |  | 1.50 | mA |
| IOPD | Output Leakage Current | $\mathrm{V}_{\text {OUT }}=5.5 \mathrm{~V}$ | 0 |  |  | 0.5 |  | 5.0 | $\mu \mathrm{A}$ |

AC ELECTRICAL CHARACTERISTICS (Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=3.0 \mathrm{~ns}$ )

| Symbol | Parameter | Test Conditions | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{T}_{\mathrm{A}}=-40$ to $85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Min | Typ | Max | Min | Max |  |
| $\mathrm{f}_{\text {max }}$ | Maximum Clock Frequency (50\% Duty Cycle) | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V} \quad \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{gathered}$ | $\begin{aligned} & 90 \\ & 85 \end{aligned}$ | $\begin{aligned} & 140 \\ & 130 \end{aligned}$ |  | $\begin{aligned} & 80 \\ & 95 \end{aligned}$ |  | MHz |
| $\begin{aligned} & \text { tpLH, } \\ & \mathrm{t}_{\mathrm{PH}} \end{aligned}$ | Maximum Propagation Delay, CP to Q | $\begin{gathered} \mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V} \quad \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{gathered}$ |  | $\begin{aligned} & 4.1 \\ & 5.6 \end{aligned}$ | $\begin{gathered} 9.4 \\ 10.4 \end{gathered}$ | $\begin{aligned} & \hline 1.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 10.5 \\ & 11.5 \end{aligned}$ | ns |
| $\begin{aligned} & \hline \mathrm{t}_{\mathrm{PzL}}, \\ & \mathrm{t}_{\text {PZH }} \end{aligned}$ | Output Enable Time, OE to Q | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V} \quad \mathrm{C}_{\mathrm{L}}=15 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \end{aligned}$ |  | $\begin{aligned} & 6.5 \\ & 7.3 \end{aligned}$ | $\begin{aligned} & 10.2 \\ & 11.2 \end{aligned}$ | $\begin{aligned} & 1.0 \\ & 1.0 \end{aligned}$ | $\begin{aligned} & 11.5 \\ & 12.5 \end{aligned}$ | ns |
| $\begin{aligned} & \text { tpLZ, } \\ & \text { tpHZ } \end{aligned}$ | Output Disable Time OE to Q | $\begin{array}{ll} \hline \mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega & \\ \hline \end{array}$ |  | 7.0 | 11.2 | 1.0 | 12.0 | ns |
| tosLh, toshl | Output to Output Skew | $\begin{array}{ll} \mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V} & \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF} \\ \text { (Note 1) } & \end{array}$ |  |  | 1.0 |  | 1.0 | ns |
| $\mathrm{C}_{\text {in }}$ | Maximum Input Capacitance |  |  | 4 | 10 |  | 10 | pF |
| $\mathrm{C}_{\text {out }}$ | Maximum 3-State Output Capacitance (Output in High-Impedance State) |  |  | 9 |  |  |  | pF |


|  |  | Typical @ $\mathbf{2 5}{ }^{\circ} \mathbf{C}, \mathbf{V _ { C C } = \mathbf { 5 . 0 V }}$ |  |
| :--- | :--- | :---: | :---: |
| $\mathrm{C}_{\mathrm{PD}}$ | Power Dissipation Capacitance (Note 2) | $\mathbf{p F}$ |  |

1. Parameter guaranteed by design. $\mathrm{t}_{\mathrm{OLLH}}=\left|\mathrm{t}_{\text {PLHm }}-\mathrm{t}_{\text {PLHn }}\right|$, $\mathrm{t}_{\mathrm{OSHL}}=\left|\mathrm{t}_{\text {PHLm }}-\mathrm{t}_{\text {PHLn }}\right|$.
2. $\mathrm{C}_{P D}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $\mathrm{I}_{\mathrm{CC}(\mathrm{OPR})}=\mathrm{C}_{P D} \bullet \mathrm{~V}_{\mathrm{CC}} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}} / 8$ (per flip-flop). $\mathrm{C}_{\mathrm{PD}}$ is used to determine the no-load dynamic power consumption; $\mathrm{P}_{\mathrm{D}}=\mathrm{C}_{\mathrm{PD}} \bullet \mathrm{V}_{\mathrm{CC}}{ }^{2} \bullet \mathrm{f}_{\mathrm{in}}+\mathrm{I}_{\mathrm{CC}} \bullet \mathrm{V}_{\mathrm{CC}}$.

NOISE CHARACTERISTICS (Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=3.0 \mathrm{~ns}, \mathrm{C}_{\mathrm{L}}=50 \mathrm{pF}, \mathrm{V}_{\mathrm{CC}}=5.0 \mathrm{~V}$ )

| Symbol | Parameter | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: |
|  |  | Typ | Max |  |
| $\mathrm{V}_{\text {OLP }}$ | Quiet Output Maximum Dynamic $\mathrm{V}_{\text {OL }}$ | 1.2 | 1.6 | V |
| $\mathrm{V}_{\text {OLV }}$ | Quiet Output Minimum Dynamic $\mathrm{V}_{\text {OL }}$ | -1.2 | -1.6 | V |
| $\mathrm{V}_{\text {IHD }}$ | Minimum High Level Dynamic Input Voltage |  | 2.0 | V |
| $\mathrm{V}_{\text {ILD }}$ | Maximum Low Level Dynamic Input Voltage |  | 0.8 | V |

TIMING REQUIREMENTS (Input $\mathrm{t}_{\mathrm{r}}=\mathrm{t}_{\mathrm{f}}=3.0 \mathrm{~ns}$ )

| Symbol | Parameter | Test Conditions | $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ |  | $\frac{T_{A}=-40 \text { to } 85^{\circ} \mathrm{C}}{\text { Limit }}$ | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | Typ | Limit |  |  |
| $\mathrm{t}_{\text {w }}$ | Minimum Pulse Width, CP | $\mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V}$ |  | 6.5 | 8.5 | ns |
| $\mathrm{t}_{\text {su }}$ | Minimum Setup Time, D to CP | $\mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V}$ |  | 2.5 | 2.5 | ns |
| $t_{\text {h }}$ | Minimum Hold Time, D to CP | $\mathrm{V}_{\mathrm{CC}}=5.0 \pm 0.5 \mathrm{~V}$ |  | 2.5 | 2.5 | ns |

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :--- | :---: | :---: |
| MC74VHCT374ADWRG | SOIC-20WB <br> (Pb-Free) | $1000 /$ Tape \& Reel |
| MC74VHCT374ADTRG | TSSOP-20 <br> (Pb-Free) | $2500 /$ Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.


Figure 3. Switching Waveform


Figure 4. Switching Waveform


Figure 5. Switching Waveform

## MC74VHCT374A


*Includes all probe and jig capacitance
Figure 6. Test Circuit


Figure 7. Test Circuit


Figure 8. Expanded Logic Diagram


SCALE 1:1


NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES

PER ASME Y14.5M, 1994
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION PROTRUSION. ALLOWABLE PROTRUSION
SHALL BE 0.13 TOTAL IN EXCESS OF B SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS |  |
| :---: | ---: | ---: |
|  | MIN | MAX |
| A | 2.35 | 2.65 |
| A1 | 0.10 | 0.25 |
| b | 0.35 | 0.49 |
| $\mathbf{c}$ | 0.23 | 0.32 |
| D | 12.65 | 12.95 |
| E | 7.40 | 7.60 |
| e | 1.27 BSC |  |
| H | 10.05 | 10.55 |
| $\mathbf{h}$ | 0.25 | 0.75 |
| L | 0.50 | 0.90 |
| $\boldsymbol{\theta}$ | $0^{\circ}$ | $7^{\circ}$ |

GENERIC
MARKING DIAGRAM*


| XXXXX | $=$ Specific Device Code |
| :--- | :--- |
| A | $=$ Assembly Location |
| WL | $=$ Wafer Lot |
| YY | $=$ Year |
| WW | $=$ Work Week |
| G | $=$ Pb-Free Package |

*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, " G " or microdot " $\mathrm{\nabla}$ ", may or may not be present.

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| ---: | :--- | :--- | :--- |
| DESCRIPTION: | SOIC-20 WB | PAGE 1 OF 1 |

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TSSOP-20 WB
CASE 948E
ISSUE D
DATE 17 FEB 2016

SCALE 2:1


1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982
CONTROLLING DIMENSION: MILLIMETER
2. DIMENSION A DOES NOT INCLUDE MOLD

FLASH, PROTRUSIONS OR GATE BURRS.
FLASH, PROTRUSIONS OR GATE BURRS.
MOLD FLASH OR GATE BURRS SHALL NO
EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE

INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. SHALL NOT EXCEED $0.25(0.010)$ PER SIDE
5. DIMENSION K DOES NOT INCLUDE

DAMBAR PROTRUSION. ALLOWABLE
DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-

|  | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 6.40 | 6.60 | 0.252 | 0.260 |
| B | 4.30 | 4.50 | 0.169 | 0.177 |
| C | --- | 1.20 | --- | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 BSC |  | 0.026 BSC |  |
| H | 0.27 | 0.37 | 0.011 | 0.015 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 | BSC | 0.252 BSC |  |
| M | 0 | $0^{\circ}$ | $8^{\circ}$ | 0 |

GENERIC MARKING DIAGRAM* НРННННННН

|  | XXXX |
| :---: | :---: |
|  | XXXX |
|  | ALYW. |
| $\bigcirc$ | - |

A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

- = Pb-Free Package
(Note: Microdot may be in either location)
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-$ Free indicator, " G " or microdot " $\mathrm{\nabla}$ ", may or may not be present.
DIMENSIONS: MILLIMETERS

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| ---: | :--- | :--- | :--- |
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